Two Type of UWB band pass filter using Periodic EBG Structure

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Abstract

In this paper two different periodic structure is used to design two UWB band pass micro strip filter .Both the EBG structures are periodic uni-planar compact-electromagnetic band gap (UC-EBG) in nature. The performance this filter is compared with insertion loss which refers to pass band pass filter. The design is done using advanced design system (ADS) in method of momentum.

Keywords: —Bandpass filter, electromagnetic bandgap (EBG), ultra wideband (UWB), wideband filter.

INTRODUCTION

The Ultra-wideband (UWB) technology is being reinvented recently with many promising modern applications. In particular, the UWB radio system has been receiving great attention from both academy and industry since the Federal Communications Commission (FCC) release of the frequency band from 3.1 to 10.6 GHz for commercial communication on applications in February 2002[1-6]. In an UWB system, an UWB band pass filter (BPF) is one of the key passive components to keep the spectrum of the signals to meet the FCC limits, or used in the UWB pulse generation and reshaping[7-11].

In such a system, an UWB filter is one of the key components, which should exhibit a wide bandwidth with low insertion loss over the whole band. In order to meet the FCC limit[12-19], good selectivity at both lower and higher frequency ends and flat group-delay response over the whole band are required. Over the last years, the design of wide and ultra-wide Bandpass filters is generating a great interest due to the fast development of broadband wireless communication systems. Traditional methods to implement ultra-wide bandpass filters usually introduce spurious bands .These un-desired bands become an important drawback for ultra-wide bandpass filters performance due to their proximity to the pass-band of interest[20-26].

The recent research and development practical applications of EBG structures have improved realizing compact EBG structures filters. EBG structure recently is developed rapidly due to its unique properties to suppress the propagation of surface wave in microstrip filters. EBG structure is also known as a high impedance surface due to its ability to suppress the propagation of surface wave at the certain operational frequency. This structure is also has ability to block the effect of mutual coupling effect in array application.

OVERVIEW OF EBG STRUCTURES

2 EBG definition.

Periodic structures are abundant in nature, which have fascinated artists and scientists alike. When they interact with electromagnetic waves, exciting phenomena appear and amazing features result. In particular, characteristics such as frequency stop bands, pass bands[27-31], and band gaps could be identified.

Electromagnetic band gap structures are defined as artificial periodic (or sometimes non-periodic) objects that prevent/assist the propagation of electromagnetic waves in a specified band of frequency for all incident angles and all polarization states.

Electromagnetic band-gap (EBG) structures are periodic structures which can prohibit the propagation of electromagnetic wave in certain band of frequency. They can be embedded in the dielectric substrate or etched on the metal layers. The EBG structures are always used to help suppress the surface waves to gain good pass band or stop band.

There are two types of EBG structure to be discussed. Firstly is Perforated dielectric and the second one is Metallodielectric structures. Perforated dielectric is defined as effectively suppress unwanted substrate mode. This structure designed by drill periodic holes on dielectric substrates to introduce another dielectric but in practical, this structure is difficult to implement. Metallodielectric structure is exhibits an attractive reflection phase future where the reflected field change continuously from 180 degrees to -180 degrees versus frequency[32-35].

ELECTROMAGNETIC BAND GAP (EBG) STRUCTURE.

EBG structures are usually realized by periodic arrangement of dielectric materials and metallic conductors. In general, they can be categorized into three groups according to their geometric configuration:

(1) Three-dimensional volumetric structures,
(2) Two-dimensional planar surfaces, and
One-dimensional transmission lines.

Mushroom-like Uni-planar

Fig 1. Various types of EBG structure

**BASIC PRINCIPLE OF EBG STRUCTURE**

The basic design of EBG structure is shown in figure 2, known as mushroom like EBG structure. This structure has frequency range where the surface impedance is very high. The equivalent LC circuit acts as a two-dimensional electric filter in this range of frequency to block the flow of the surface waves. The inductor L results from the current flowing through the visa, and the capacitor C due to the gap effect between the adjacent patches. Thus, the approach to increase the inductance or capacitance will naturally result in the decrease of band-gap position[36-41].

3. FILTER THEORY

In designing a filter, the following important parameters are generally considered.

- Pass bandwidth
- Stop band attenuation and frequencies
- Input and output impedances
- Return loss
- Insertion loss
- Group delay

The most important parameters among the above is the amplitude response given in terms of the insertion loss Vs frequency characteristics. Let Pi be the incident power at the filter input , Pr is the reflected power, PL is the power passed on to the load. The insertion loss of the filter is defined by,

\[ IL \,(dB) = 10 \log \left( \frac{P_i}{P_L} \right) = -10 \log \left( 1 - |\Gamma|^2 \right) \]

Where PL=Pi - Pr, if the filter is lossless and \(\Gamma\) is the voltage reflection coefficient given by |\(\Gamma\)|\(^2\) = Pr/Pi

The return loss of the filter is defined by

\[ RL \,(dB) = 10 \log \left( \frac{P_i}{P_r} \right) = -10 \log \left( |\Gamma|^2 \right) \]

which quantifies the amount of impedance matching at the input port.

The group delay is important for the multi-frequency or pulsed signals to determine the frequency dispersion or deviation from constant group delay over a given frequency band and is defined by

\[ T_d = \left[ \frac{1}{2\pi} \right] \frac{d\Phi_t}{df} \]

Where \(\Phi_t\) is the transmission phase.

4. TWO PROPOSED EBG STRUCTURE.

The conventional EBG structure has a wide band-gap and compact nature. The inductor L results from the current flowing through the connecting via. The gap between the conductor edges of two adjacent cells introduces equivalent capacitance \(C\). Thus a two dimensional periodic LC network is realized which results in the frequency band-gap and the center frequency of the band-gap is determined by the formula

\[ \omega = \frac{1}{\sqrt{LC}} \]

From above equation it can be seen that in order to achieve an even more compact EBG structure, the equivalent capacitance \(C\) and inductance \(L\) should be increased. But in the EBG design procedure, if the dielectric material and its thickness have been chosen, the inductance \(L\) cannot be altered[42-45]. Therefore, only the capacitance \(C\) can be enlarged.

Below fig 3 shows the proposed EBG structures for filter design.
DESIGN OF PROPOSED UWB FILTERS

In this proposed model two uwb band pass filter are designed and simulated also compared with their insertion loss. All BPFs are fabricated with thickness of 0.635 mm on an RT/Duroid substrate with a dielectric constant of 10.2. The schematics of two uniplanar compact–EBG (UC–EBG) structures are shown in fig 4. The inter digital coupled lines used in all BPFs have a coupling peak at the center frequency of 6.85 GHz. There simulation as been done using ADS Momentum simulator.

V. SIMULATION RESULTS

Fig 4. Two Periodic UC–EBG structure BPF

Fig 5. Insertion loss of first structure

Fig 6 Insertion loss of second structure

VI. CONCLUSION

In this, two periodic EBG structures are investigated and applied to UWB BPFs. The UC–EBG cell, used here as improved passband obtained in UWB region, also improving the good out-of-band performances. It is also observed that different structures possess different characteristics. The result have been compared by simulated using ADS Momentum simulator.

REFERENCE

4. Parameswari, D., Khanaa, V., Deconstructing model checking with hueddot, International Journal of


17. Peter, M., Thooyamani, K.P., Srinivasan, V., A study on performance of the commodity market based on technicalanalysis, International Journal of Pure and
32. Prakash, S., Sherine, S., Forecasting methodologies of solar resource and...


